

Standard Diodes, 250 A (MAGN-A-PAK Power Modules)



MAGN A-PAK

FEATURES

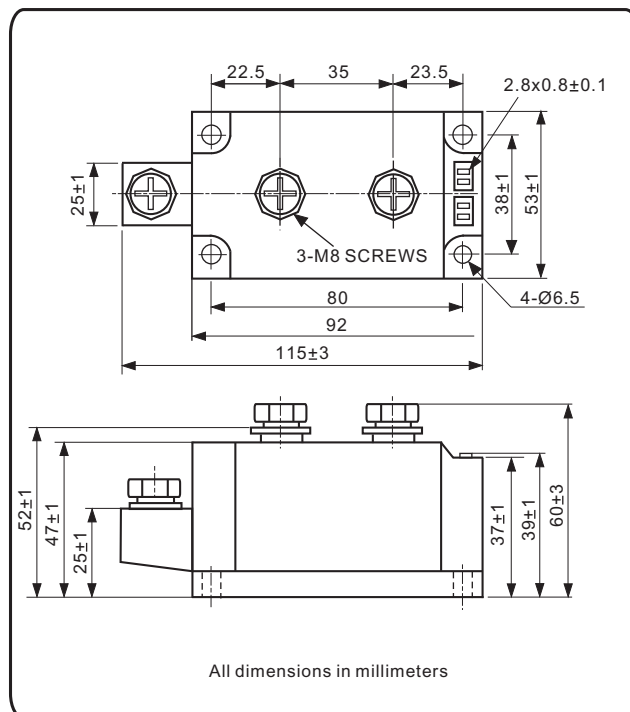
- UL approved file E320098 
- High current capability
- High surge capability
- High voltage ratings up to 2000 V
- 3000 V_{RMS} isolating voltage with non-toxic substrate
- Industrial standard package
- Compliant to RoHS 

APPLICATIONS

- Rectifying bridge for large motor drives
- Rectifying bridge for large UPS
- Rectifying power supplier
- Frequency converters

PRODUCT SUMMARY

I _{F(AV)}	250 A
Type	Modules - Diode, High Voltage



MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}		250	A
	T _C	100	°C
I _{F(RMS)}		392	A
	T _C	100	°C
I _{FSM}	50 Hz	11000	A
	60 Hz	11600	
I ² t	50 Hz	605	kA
	60 Hz	552	
I ² ·t		6050	kA ² ·t
V _{RRM}	Range	800 to 2000	V
T _{Stg} , T _J	Range	- 40 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT T_J MAXIMUM mA
NKD250 NKJ250 NKC250	08	800	900	20
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	

FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			250	A	
					100	°C	
Maximum RMS forward current	I _{F(RMS)}	180° conduction, half sine wave at T _C = 100 °C			392	A	
Maximum peak, one-cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	11.0	kA	
		t = 8.3 ms			11.6		
Maximum I ² t for fusing	I ² t	t = 10 ms			100 % V _{RRM} reapplied	605	kA ² s
		t = 8.3 ms				552	
		t = 10 ms	100 % V _{RRM} reapplied		424		
		t = 8.3 ms			390		
Maximum I ² /t for fusing	I ² /t	t = 0.1ms to 10 ms, no voltage reapplied			6050	kA ² /t	
Maximum forward voltage drop	V _{FM}	I _{pk} = 1000 A, T _J = 25 °C, 10µs sine pulse			1.40	V	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
RMS insulation voltage	V_{INS}	t = 1 s	3000	V
Maximum peak reverse and off-state leakage current	I_{RRM}	$T_J = T_J$ maximum, rated V_{RRM} applied	20	mA
		$T_J = 25\text{ °C}$	20	µA

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T_J , T_{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case per junction	R_{thJC}	DC operation	0.14	K/W
Maximum thermal resistance, case to heatsink	R_{thC-hs}		0.044	
Mounting torque ± 10 %	SMAP to heatsink, M6	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	4	Nm
	busbar to MAP, M8		12	
Approximate weight			900	g
Case style		See dimensions - link at the end of datasheet	MAGN-A-PAK	

Fig.1 On-state current vs. voltage characteristic

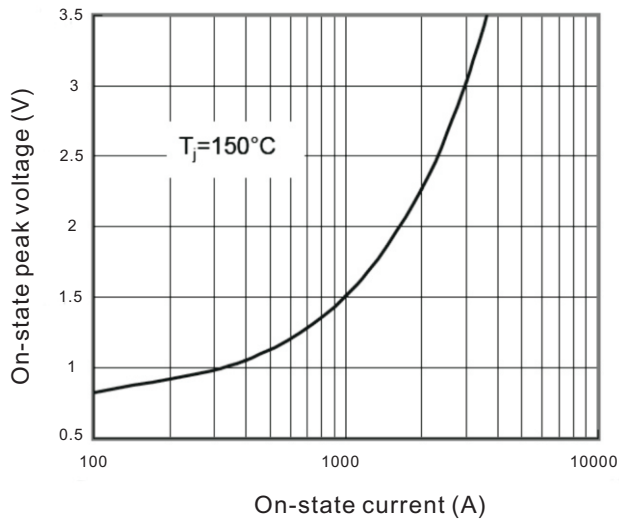


Fig.2 Transient thermal impedance(junction-case)

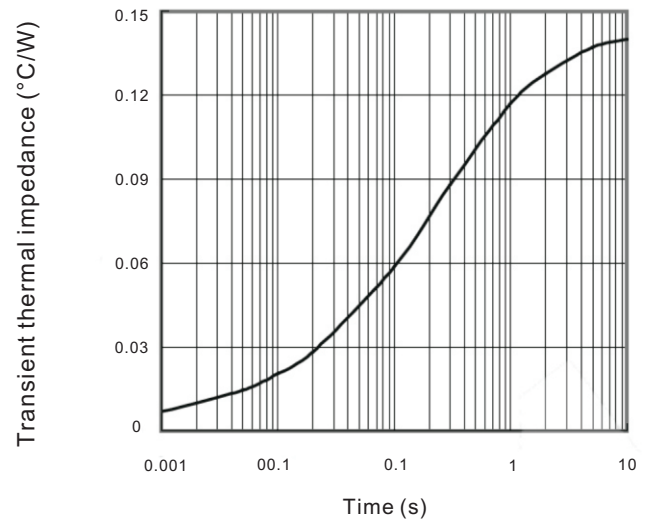


Fig.3 Power consumption vs. average current

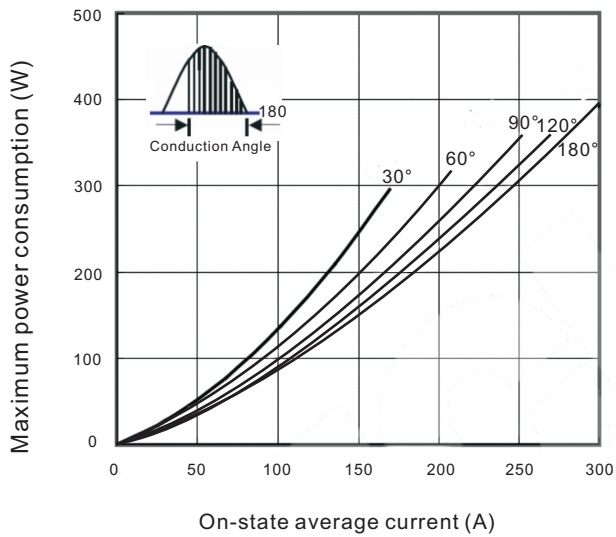


Fig.4 Case temperature vs. on-state average current

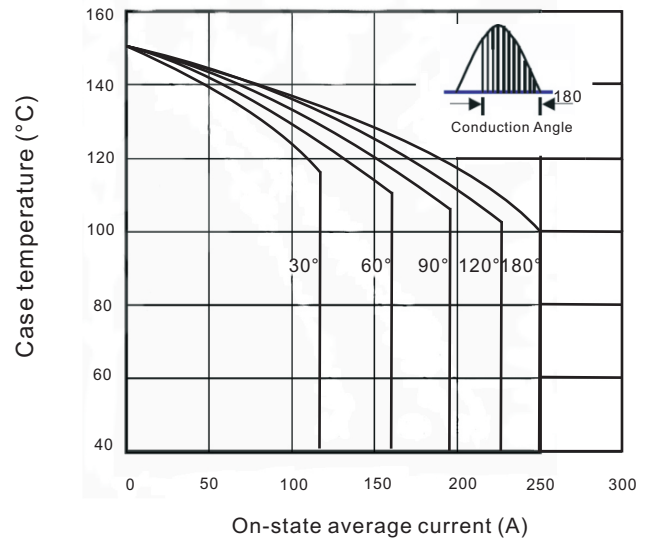


Fig.5 On-state surge current vs. cycles

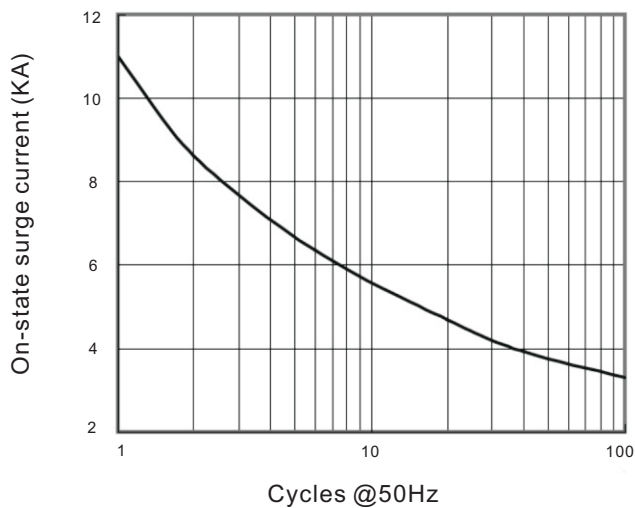


Fig.6 I^2t Characteristic

